NSN 5961-01-038-5136

Fiig: A110a0



Diode Semiconductor Device - Page 1 of 1 View Online at https://aerobasegroup.com/nsn/5961-01-038-5136 **Inclosure Material:** Glass **Overall Length:** Between 0.293 inches and 0.357 inches **Terminal Length:** 1.000 inches **Overall Diameter:** Between 0.215 inches and 0.235 inches **End Application:** An/grn27 Joint Electronic Device Engineering Council/jedec/case Outline Designation: Do-13 **Mounting Method: Terminal Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 33.0 breakdown voltage, dc **Current Rating Per Characteristic:** 1.00 milliamperes forward current, average peak **Power Rating Per Characteristic:** 1.0 watts small-signal input power, common-collector **Special Features:** Transient suppressor **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** Yes - demil/mli